H ot Spots and P seudogaps for H ole- and E lectron-D oped H igh-Tem perature Superconductors.

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U sing cluster perturbation theory, it is shown that the spectral weight and pseudogap observed at the Ferm i energy in recent Angle Resolved Photoem ission Spectroscopy (ARPES) of both electron and hole-doped high-tem perature superconductors in their natural explanation within the t-t⁰-t⁰-U H ubbard m odel in two dimensions. The value of the interaction U needed to explain the experiments for electron-doped systems at optim all doping is in the weak to intermediate coupling regime where the t J m odel is inappropriate. At strong coupling, short-range correlations su de to create a pseudogap but at weak coupling long correlation lengths associated with the antiferrom agnetic wave vector are necessary.

D eep insight into the nature of strongly correlated electron m aterials, such as high tem perature superconductors, has em erged in the last few years from both experim ent and theory. On the experim ental side, ARPES [1] and scanning-tunneling experim ents [2] provide us with detailed information on the nature of single-particle states. This information must be explained by theory if we are to understand correlated m aterials. For exam – ple, contrary to one of the central tenets of Fem i liquid theory, sharp zero-energy excitations are not enclosing a de nite volume in the B rillouin zone. C ertain directions are alm ost com pletely gapped while others are not. This is the fam ous pseudogap problem that has been the focus of much attention in the eld [3].

On the theoretical side, Dynam ical Mean-Field Theory (DMFT) [4] has allowed us to understand the evolution of single-particle states during the interactioninduced (M ott) transition between m etallic and insulating states [5] (parent com pounds of high-tem perature superconductors are M ott insulators). Generalizations of DMFT, such as the Dynamical Cluster Approximation (DCA) [6] and Cellular-DMFT [7] are how ever necessary to take into account the m om entum dependence of the self-energy that is neglected in DMFT and is clearly apparent in ARPES experiments [1]. Up to now, these calculations have been restricted to hole-doped system s and small system sizes or to the perfectly nested case. The nature of single-particle excitations, and in particular the pseudogap in cuprate superconductors, is thus still an open theoretical problem .

W ithout any assumption about the nature of the ground state, we show that the Hubbard model with xed rst-, second- and third-neighbor hopping (t, t⁰ and t⁰⁰) accounts for the strikingly di erent locations of low energy excitations observed experimentally in holeand electron-doped cuprate superconductors [8, 9]. At zero doping we have a M ott insulator with a large U. By contrast with previous attempts to obtain a uni ed m odel [10], we will see that the interaction strength U varies as one m oves from the hole-doped to the electron-

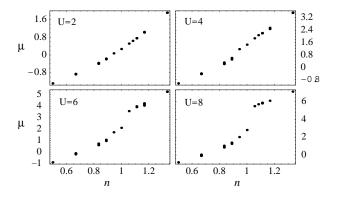


FIG.1: Chem ical potential calculated at various dopings using CPT, in units of t, the NN hopping. For this gure only, $t^0 = 0.4t$ and $t^{00} = 0$.

doped system s. That parameter should be at least of the order of the bandwidth for hole-doped system s. In this case the pseudogap is controlled mainly by M ott Physics with short-range correlations. The situation is similar for underdoping with electrons. A swe approach the optim ally-doped electron case, the pseudogap occurs at a smaller coupling where M ott Physics is not essential. Long correlation lengths then play an essential role in creating the pseudogap whereas in the strong coupling case they are not necessary for the pseudogap to appear. These results give insight into two di erent m echanism s for the pseudogap phenom enon and into the nature of the breakdown of Ferm i-liquid theory in these system s. W e also gain insight into the appropriate m icroscopic m odel of high-tem perature superconductors.

M odel and m ethodology. We study the square lattice H ubbard m odel with on-site C oulom b repulsion U. We set the rst-neighbor hopping t to unity, and introduce second-neighbor (diagonal) hopping $t^0 = 0.3t$ and third-neighbor hopping $t^0 = 0.2t$, as suggested by band structure calculations [11]. The diagonal hopping t^0 is a key ingredient to understand the P hysics, even though its precise value can vary slightly between di erent com pounds.

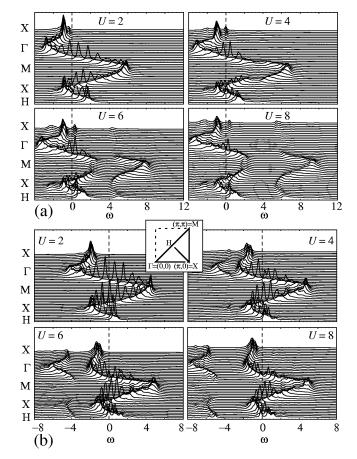


FIG. 2: Single particle spectral weight, as a function of energy ! in units oft, for wavevectors along the high-sym metry directions shown in the inset. (a): CPT calculations on a 3 4 cluster with 10 electrons (17% hole doped). (b): the same, with 14 electrons (17% electron doped). In all cases we use $t^0 = 0.3t$ and $t^{00} = 0.2t$. A Lorentzian broadening = 0.12t is used to reveal the otherwise delta peaks.

It frustrates antiferrom agnetic (AFM) order and rem oves particle-hole sym m etry, thereby also allowing the AFM zone boundary to cross the Ferm i surface. The thirdneighbor hopping t^{00} m akes the Ferm i surface slightly bulge away from the intersection with the AFM zone boundary, as observed experimentally [8], and m akes low – energy excitations m ore stable along the diagonal of the B rillouin zone.

We use Cluster Perturbation Theory [12] (CPT) to gain insight into the single-particle states of the Hubbard model and their relation to cuprate superconductors. The method can reproduce the spin-charge separation of one dimensional systems [12] as well as the dispersion relations obtained in the large U limit. It reduces to the exact result at U = 0 and in the atom ic limit ($t_{ij} = 0$). It is based on exact diagonalizations of nite clusters that are coupled through strong-coupling perturbation theory. It basically amounts to replacing the exact self-energy by that of the cluster only [13]. The G reen function calculated by CPT is made up of a set

of discrete poles, like in ordinary exact diagonalizations, except that (i) more poles have substantial weight and (ii) they disperse continuously with wavevector, allowing for clearmomentum distribution curves. The results presented here were calculated on 12-site rectangular clusters. The resulting G reen function is averaged over the (3 4) and (4 3) clusters to recover the original sym metry of the lattice. We checked that the main features are the same when using clusters of dierent shapes. Our nite energy resolution, of about 0:12t, does not allow us to resolve elects related to superconductivity. We com pare with ARPES experiments of similar resolution.

The M ott transition. We begin in Fig. 1 with a plot of the chemical potential as a function of doping for various values of the interaction strength. The di erent results in this gure are obtained from clusters of di erent sizes ranging from 4 to 13 sites with varying geom etry. The sm ooth behavior of the function away from half-lling shows that the cluster sizes are large enough to provide reliable results. There is a jump in when U is large enough, namely above U = 6t roughly. The jump in does not follow from a long-range ordered ground state since the basic clusters are nite. It is instead a clear manifestation of the M ott phenom enon.

Fig. 2 displays the single-particle spectral weight A (k;!) as a function of energy for wave vectors k along the high-symmetry directions shown in the inset. Only the ! < 0 domain of A (k; !) is accessible to ARPES. Fig. 2(a) illustrates the e ect of increasing interaction strength on a near optimally hole-doped system while Fig. 2(b) does the same in the electron-doped case. C learly, there is a range of frequencies where A (k;!) = 0for all wave vectors. This is the Mott gap. At nite doping it always opens up away from zero energy when U is su ciently large. In the electron-doped case, ! = 0 is in the upper Hubbard band. The lower Hubbard band is at negative energies, as has been observed in ARPES [14]. The overall narrowing of the band just below the Fermi level is more in portant in the electron-doped case. A lso, the shape of the dispersion is di erent from that obtained in a mean-eld AFM state [15] and there is no clear doubling of the dispersion relation of the type that occurs in one dimension when there is spin-charge separation.

Ferm i surface plots and pseudogap. We now move to the main point of our paper, namely the pseudogap and hot spots. The top two panels of Fig. 3 for a 17% holedoped system represent the strength of A (k;!) at ! = 0. A sa function of interaction strength, the intensity disappears gradually near the (;0) and (0;) points, leaving zero-energy excitations only near the diagonal. Large values of U (U > 8t) seem necessary to reproduce the experim entally observed spectral function of hole-doped system s [9], even more so on a 11% doped system (not shown). The lower panels show the imaginary part of the self-energy (or scattering rate) corresponding to the momentum dispersion curve right above. For U = 2t,

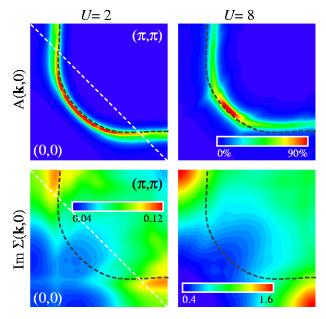


FIG. 3: (color) Top: Intensity plot of the spectral function at the Fermi level, in the rst quadrant of the Brillouin zone, for a 17% hole-doped system (10 electrons on a 3 4 cluster). Here $t^0 = 0.3t$ and $t^{00} = 0.2t$ (the gray dashed line is the non-interacting Fermi surface). Bottom : Im aginary part of the self-energy (in units of t) corresponding to the same parameters as the top plot. A Lorentzian broadening is used: = 0:12t (top) and = 0:4t (bottom).

the self-energy is very sm all overall, but has a maximum along the Ferm isurface where the Ferm ivelocity is sm allest (density of states largest); this illustrates how we depart from the Ferm i liquid picture (in which $^{(0)}(0) = 0$) as we move towards interm ediate coupling. At U = 8t, the scattering rate is much larger and a ects larger regions separated by roughly (;). In all cases a higher scattering rate leads to rem oval of spectral weight.

The electron-doped case is displayed in Fig. 4 for 17% doping. At m oderate U, the spectral intensity drops only at the intersection of the AFM B rillouin zone with the Ferm i surface. However, for larger U, only the neighborhoods of (;0) and (0;) survive. The latter situation is analogous to that observed by ARPES in electron underdoped systems and can be reproduced by calculations (not shown) with U large at 11% doping. At optimal doping how ever, ARPES results [14] look instead qualitatively like the upper left panel of Fig. 4.

H ot spots and pseudogap. The Ferm i-surface points where the intensity decreases (Fig.4) are called hot spots. How ever, a pseudogap is characterized not only by lower intensity at the Ferm i energy, but also by a dispersive peak that stops short of crossing the Ferm i surface. This experimentally well-known phenomenon is illustrated on Fig.5, which show senergy dispersion curves forwave vectors along the (;0) (; =2) stretch in the hole-doped case (left) and along the diagonal in the electron-doped case (right). For small values of U, a well-de ned quasi-

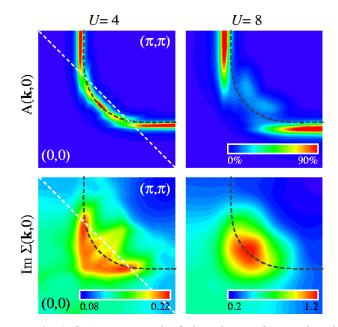


FIG. 4: (color) Same as Fig. 3, but for an electron-doped system (14 electrons on a 3 4 cluster). The white dashed line on the left panels is the AFM zone boundary, showing the coincidence of hot spots with the intersection of this line with the Fermi surface.

particle exists at the Ferm i level (! = 0). At stronger coupling (U = 8t), a pseudogap comparable to experimental observation is clearly visible at the Ferm i level.

D iscussion: strong- and weak-coupling pseudogaps. As in previous studies, the strong-coupling pseudogap [16] is concom itant with the M ott gap but is clearly distinct from the latter. The M ott gap is a purely local (onsite) phenom enon that occurs for all wave vectors and is not tied to ! = 0. By contrast, the pseudogap occurs around ! = 0 and only in regions of the Ferm i surface that are connected to other such regions by wave vectors that have a broad spread of radius around (;). The di erence in the location of the pseudogap between hole-and electron underdoped cuprates follow sby sim ply nding which points of the Ferm i surface can be connected by (;), within , to other Ferm i surface points.

D espite the importance of (;), the strong-coupling pseudogap is not caused by long-range AFM correlations. Indeed, (a) O ur lattices do not exhibit long-range order (b) W e veri ed that the results are not very sensitive to t^0 (frustration) (c) Fig. 5 shows that at U > 8t the pseudogap is of order t, only weakly dependent on U and does not scale as the antiferrom agnetic coupling $J = 4t^2=U$, in contrast with previous studies [16, 17]. This pseudogap would therefore persist in the U ! 1 limit of the H ubbard m odel, where hopping between sites is constrained by the impossibility of double occupancy and where t is the relevant energy scale. For a case where it is possible to study the size dependence of the strong-coupling pseudogap at xed doping, we veri ed that the

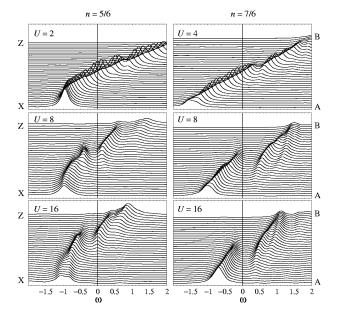


FIG. 5: Left: Spectral function for the hole doped system illustrated in Figs.2a and 3 plotted as a function of energy, for wavevectors along the direction X = (; 0) to Z = (; =2). At U = 2t (top), a depression in the spectral function is visible slightly away from ! = 0, while the pseudogap is fully opened at U = 8t (m iddle). R ight: Spectral function for the electron-doped system illustrated in Figs 2b and 4, plotted along the diagonal of the B rillouin zone, from A = (0:3; 0:3) to B = (0:7; 0:7). The results for the experimentally relevant electron underdoped system are sim ilar.

results are size independent, suggesting again the shortrange nature of the phenom enon. Longer range correlations at the AFM wave vector might only reinforce the strong-coupling pseudogap that already exists in the presence of short-range correlations. The location of this strong-coupling pseudogap, in both electron- and holedoped cases, coincides with the predictions of the um klapp m echanism [18], which does not need long-range correlations. How ever, a proper strong-coupling extension of the um klapp m echanism is still needed.

Signs of a pseudogap also occur at weak coupling. This is illustrated by the hot spots that are visible in the electron-doped case at U = 4t in Fig. 4, upper panel. Contrary to the U = 8t case, these hot spots (a) are located precisely at the intersection with the AFM zone boundary (b) they generally correspond to a cluster shape dependent depression in A (k;!) and not to a genuine pseudogap. W e attribute these results to the short correlation lengths (lim ited to the cluster size) in CPT and conclude that we are seeing the onset of the true pseudogap that, as expected from the presence of true gaps in the itinerant antiferrom agnet [19], would be induced by large AFM correlation lengths [20]. We nd, as in Ref. [20], that the interaction strength U cannot be 6t to preserve this kind of pseudogap larger than U where ! = 0 excitations persist near the diagonal.

Since experiments on optim ally-doped electron superconductors do nd large AFM correlation lengths [21] as well as ! = 0 single-particle excitations [8] near the diagonal, the pseudogap mechanism in this case should be the weak-coupling one (U . 6t) [19, 20]. This value of U is smaller than, but not too di erent from, that necessary for a sizeable M ott gap at half-lling. This may be understood as follows. The contribution to the value of U that comes from simple Thom as-Ferm i screening scales like (@ =@n). Fig. 1 clearly shows that this quantity, beginning at U > 4t, is smaller for electron-doped than for hole-doped system s, dem onstrating the internal consistency of a picture where the value of U decreases as one goes from the hole-to the electron-doped system s. R ef. [20] presents additional argum ents for a smaller U.

To summarize, we illustrated two ways in which a Fermiliquid can be destroyed by a pseudogap and found that a uni ed picture of A (k;!) in the cuprates emerges from the t t⁰ t⁰⁰ U model if we allow U to decrease as the concentration of electrons increases.

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